

LC4120NV

LCD Power Supply Switching IC

Overview

The LC4120NV is an LCD power supply switching IC that provides 3 input channels and 6 output channels. It is fabricated in an 80-V high-voltage CMOS process and features low power dissipation, high speed, and a low output impedance. This IC is optimal for switching the row driver LCD drive voltage in a wide range of LCD products.

Features

- 3 input channels/6 output channels
- Logic voltage: 2.7 to 5.5 V
- Output voltage: 80 V (maximum)
- Output impedance: 110Ω (maximum) (When $V_{HA} - V_{LA} = 60$ V)
- Output delay time: 0.5 µs (maximum)
- Operating temperature: -20 to 75°C
- Package: 20-pin SSOP

Specifications

Package Dimensions

unit: mm

3179A-SSOP20



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Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{DD} max	V _{DD}	-0.3 to +7.0	V
	V _{HA, B} –V _{LA, B}	V _{HA, B} /V _{LA, B}	-0.3 to +85	V
	V _{HA} /V _{HB}	V _{HA} /V _{HB}	-0.3 to +45.0	V
	V _{LA} /V _{LB}	V _{LA} /V _{LB}	-40.0 to +0.3	V
Input voltage	V _{IN}	S1 to S3	-0.3 to V _{DD} +0.3	V
Operating temperature	Topr		-20 to +75	°C
Storage temperature	Tstg		-40 to +125	°C

Electrical Characteristics

DC Characteristics at Ta = -20 to 75° C, $V_{SS} = 0$ V, $V_{DD} = 2.7$ to 5.5 V unless otherwise specified

(The following conditions must hold at all times: $V_{HA} \ge V_{HB} > V_{DD} > V_{SS} > V_{LB} \ge V_{LA}$.)

Parameter	Symbol	Conditions	Ratings			Linit
Falallelel	Symbol	Symbol	min	typ	max	Unit
	V _{DD}	V _{DD}	2.7	5.0	5.5	V
Operating voltage	V _{HA, B} -V _{LA, B}	V _{HA, B} , V _{LA, B}	40.0		80.0	V
	V _{HA} , V _{HB}	V _{HA} , V _{HB}	20.0		42.5	V
	V _{LA} , V _{LB}	V _{LA} , V _{LB}	-37.5		-20.0	V
Potential difference	V _{HA} –V _{HB}	V _{HA} , V _{HB}	0		5.0	V
	V _{LA} –V _{LB}	V _{LA} , V _{LB}	0		5.0	V
Input high-level voltage	V _{IH}	S1 to S3	$V_{DD} imes 0.8$		V _{DD}	V
Input low-level voltage	V _{IL}	S1 to S3	0		$V_{DD} \times 0.2$	V
Output high-level voltage	R _{OHA}	$V_{OUT} = V_{HA} - 0.5$: V_H1 to $V_H3 *1$		70	110	Ω
	R _{OHB}	$V_{OUT} = V_{HB} - 0.5$: $V_{H}1$ to $V_{H}3 * 1$		70	110	Ω
Output low-level voltage	R _{OLA}	$V_{OUT} = V_{LA} + 0.5$: V _L 1 to V _L 3 *2		70	110	Ω
	R _{OLB}	$V_{OUT} = V_{LB} + 0.5$: V _L 1 to V _L 3 *2		70	110	Ω
Current drain	IDDOPE	f = 40 kHz, Input signals operating *3			80	μA
	I _{HOPE}	f = 40 kHz, Input signals operating *3			600	μA
	I _{HLEAK}	f = 40 kHz, Input signals stopped *3	-10		+10	μA

Notes: 1. $V_{HA} - V_{LA} = 60 V$, $V_{HA} - V_{HB} = 1.0 V$ 2. $V_{HA} - V_{LA} = 60 V$, $V_{LA} - V_{LB} = 1.0 V$ 3. $V_{HA} - V_{LA} = 60 V$, $V_{HA} - V_{HB} = V_{LA} - V_{LB} = 1.0 V$

Block Diagram



Pin Assignment



Pin Functions

Pin	I/O	Function	Signal voltage
V _H 1	0	High-voltage output 1	V _{HA} /V _{HB}
V _H 2	0	High-voltage output 2	V _{HA} /V _{HB}
V _H 3	0	High-voltage output 3	V _{HA} /V _{HB}
V _L 1	0	Low-voltage output 1	V_{LA}/V_{LB}
V _L 2	0	Low-voltage output 2	V_{LA}/V_{LB}
V _L 3	0	Low-voltage output 3	V_{LA}/V_{LB}
S1	I	Logic input 1	V _{DD} /V _{SS}
S2	I	Logic input 2	V _{DD} /V _{SS}
S3	I	Logic input 3	V _{DD} /V _{SS}
V _{HA}		High-voltage power supply A	
V _{HB}		High-voltage power supply B	
V _{LA}		Low-voltage power supply A	
V _{LB}		Low-voltage power supply B	
V _{DD}		Logic system power supply	
V _{SS}		Logic system ground	

Truth Table

Input signal	Output			
Sn	V _{Hn}	V _{Ln}		
Н	V _{HA}	V _{LA}		
L	V _{HB}	V _{LB}		
(n = 1, 2, 3				

AC Characteristics



Conditions 1 at Ta = -20 to 75°C, $V_{SS} = 0 V$, $V_{DD} = 2.7$ to 5.5 V, $V_{HA} = 42.5 V$, $V_{HB} = 37.5 V$, $V_{LA} = -37.5 V$, $V_{LB} = -32.5 V$, $C_L = 50 pF$,unless otherwise specified

Parameter	Symbol	Conditions	Ratings			- Unit
	Symbol	Conditions	min	typ	max	
Output rise time	t _{TLH}			80	160	ns
Output fall time	t _{THL}			80	160	ns
High-level transmission delay time	t _{PLH}			200	500	ns
Low-level transmission delay time	t _{PHL}			200	500	ns
Input rise and fall times	t _r /t _f				30	ns

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